

6F(R) SERIES

STANDARD RECOVERY DIODES

Stud Version

Features

- High surge current capability
- Avalanche types available
- Stud cathode and stud anode version
- Wide current range
- Types up to 1200V V_{RRM}

6 A

Typical Applications

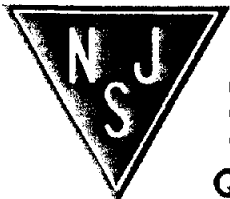
- Battery charges
- Converters
- Power supplies
- Machine tool controls

Major Ratings and Characteristics

Parameters	6F(R)	Units
$I_{F(AV)}$	6	A
@ T_C	160	$^{\circ}C$
$I_{F(RMS)}$	9.5	A
I_{FSM} @ 50Hz	159	A
@ 60Hz	167	A
i^2t @ 50Hz	134	A^2s
@ 60Hz	141	A^2s
V_{RRM} range	100 to 1200	V
T_J range	- 65 to 175	$^{\circ}C$

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Quality Semi-Conductors



ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} : maximum repetitive peak reverse voltage V	V_{RSM} : maximum non-repetitive peak reverse voltage V	$V_{R(BR)}$: minimum avalanche voltage V (1)	I_{RRM} max. @ $T_c = 175^\circ\text{C}$ mA
6F(R)	10	100	150	--	12
	20	200	275	--	
	40	400	500	500	
	60	600	725	750	
	80	800	950	950	
	100	1000	1200	1150	
	120	1200	1400	1350	

(1) Avalanche version only available from V_{RRM} 400V to 1200V.

Forward Conduction

Parameter	6F(R)	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	6	A	180° conduction, half sine wave
	160	$^\circ\text{C}$	
$I_{F(RV(S))}$ Max. RMS forward current	9.5	A	
P_R Maximum non-repetitive peak reverse power	4	KW	10 μs square pulse, $T_J = T_J \text{ max}$ see note (2)
I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current	159	A	t = 10ms No voltage
	167		t = 8.3ms reapplied
	134		t = 10ms 100% V_{RRM}
	141		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	127	A^2s	t = 10ms No voltage
	116		t = 8.3ms reapplied
	90		t = 10ms 100% V_{RRM}
	82		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	1270	A^2s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO;1)}$ Low level value of threshold voltage	0.63	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ max}$.
$V_{F(TO;2)}$ High level value of threshold voltage	0.86		$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ max}$.
r_{T1} Low level value of forward slope resistance	15.7	$\text{m}\Omega$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ max}$.
r_{T2} High level value of forward slope resistance	5.6		$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ max}$.
V_{FM} Max. forward voltage drop	1.10	V	$I_{pk} = 19\text{A}$, $T_c = 25^\circ\text{C}$, $t_p = 400\mu\text{s}$ rectangular wave

(2) Available only for Avalanche version, all other parameters the same as 6F.

Thermal and Mechanical Specifications

Parameter	6F(R)	Units	Conditions
T_J Max. junction operating temperature range	-65 to 175	°C	
T_{stg} Max. storage temperature range	-65 to 200		
R_{thJC} Max. thermal resistance, junction to case	2.5	K/W	DC operation
R_{thCS} Max. thermal resistance, case to heatsink	0.5		Mounting surface, smooth, flat and greased
T Mounting torque, $\pm 10\%$	1.2 (1.5)	Nm	Lubricated threads (Not lubricated threads)
wt Approximate weight	7 (0.25)	g (oz)	
Case style	DO-203AA (DO-4)		See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.34	0.29	K/W	$T_J = T_{J \text{ max}}$
120°	0.44	0.48		
90°	0.57	0.63		
60°	0.85	0.88		
30°	1.37	1.39		

Ordering Information Table

Device Code					
1	2	3	4	5	6
A	6	F	R	120	M
1	2	3	4	5	6
1	- A = Avalanche diode None = Standard diode				
2	- Current rating: Code = $I_{F(AV)}$				
3	- F = Standard device				
4	- None = Stud Normal Polarity (Cathode to Stud) R = Stud Reverse Polarity (Anode to Stud)				
5	- Voltage code: Code x 10 = V_{RRM} (See Voltage Ratings table)				
6	- None = Stud base DO-203AA (DO-4) 10-32UNF-2A M = Stud base DO-203AA (DO-4) M5 X 0.8 - (Not available for Avalanche diodes)				

Outlines Table

